

UNISONIC TECHNOLOGIES CO., LTD

MGBR20L50 Preliminary DIODE

MOS GATED BARRIER RECTIFIER

■ DESCRIPTION

The UTC MGBR20L50 is a surface mount mos gated barrier rectifier, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed etc.

The UTC MGBR20L50 suitable for supply applications.

■ FEATURES

- * Low forward voltage drop
- * High switching speed

TO-220-2 DFN5060-8 TO-277

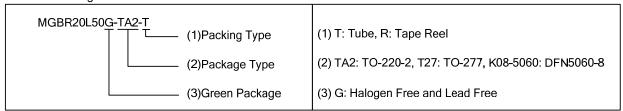
■ SYMBOL

TO-220-2 / DFN5060-8	TO-277
2 — 1 K	1. A °———— 2. K

■ ORDERING INFORMATION

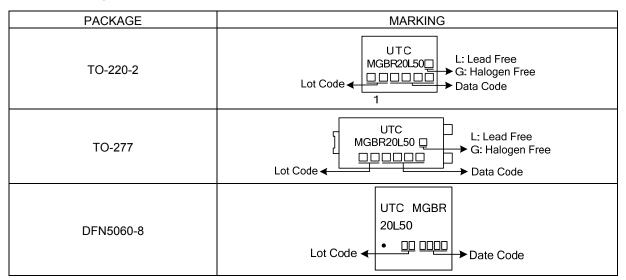
Ordering Number		Dookogo	Pin Assignment							Dooking		
Lead Free	Halogen Free	Package		2	3	4	5	6	7	8	Packing	
MGBR20L50L-TA2-T MGBR20L50G-TA2-T		TO-220-2	Κ	Α	1	-	-	ı	-	-	Tube	
MGBR20L50L-T27-T	MGBR20L50G-T27-T	TO-277	Α	Κ	Α	-	ı	1	-	ı	Tape Reel	
MGBR20L50L-K08-5060-R	MGBR20L50G-K08-5060-R	DFN5060-8	Α	Α	Α	NC	Κ	Κ	Κ	Κ	Tape Reel	

Note: Pin Assignment: A: Anode K: Cathode



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■ MARKING



■ **ABSOLUTE MAXIMUM RATINGS** (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
DC Blocking Voltage	V_{RM}	50	V
Working Peak Reverse Voltage	V_{RWM}	50	V
Peak Repetitive Reverse Voltage	V_{RRM}	50	V
Average Rectified Forward Current (Rated VR-20Khz Square Wave) - 50% Duty Cycle	Io	20	Α
Peak Forward Surge Current - 1/2 60hz	I _{FSM}	250	Α
Peak Repetitive Reverse Surge Current (2uS-1Khz)	I _{RRM}	2	Α
Maximum Rate of Voltage Change (at Rated V _R)	dv/dt	10000	V/µS
Operating Junction Temperature	T_J	-65~+150	°C
Storage Junction Temperature	T _{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT	
	TO-220-2		60		
Junction to Ambient	TO-277	θ_{JA}	73 (Note 3)	°C/W	
	DFN5060-8		72		

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I _R =0.50mA	50			V
Forward Voltage	VEM	I _F =20A, T _J =25°C			0.63	V
		I _F =20A, T _J =125°C			0.58	٧
Reverse Current (Note 1)	I_{RM}	V _R =50V, T _J =25°C			300	μΑ
		V _R =50V, T _J =125°C			100	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

- 2. Thermal resistance junction to case mounted on heatsink.
- 3. Mounted on an FR4 PCB, single-sided copper, with 100 cm² copper pad area.

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